Structure, Properties, and Theoretical Electronic Structure of UCuOP and NpCuOP

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The compounds UCuOP and NpCuOP have been synthesized and their crystal structures were determined from low-temperature single-crystal X-ray data. These isostructural compounds crystallize with two formula units in space group P4/nmm of the tetragonal system. Each An atom (An = U or Np) is coordinated to four O and four P atoms in a distorted square antiprism; each Cu atom is coordinated to four P atoms in a distorted tetrahedron. Magnetic susceptibility measurements on crushed single crystals indicate that UCuOP orders antiferromagnetically at 224(2) K. Neutron diffraction experiments at 100 and 228 K show the magnetic structure of UCuOP to be type AFI (+ − − −) where ferromagnetically aligned sheets of U atoms in the (001) plane order antiferromagnetically along [001]. The electrical conductivity of UCuOP exhibits metallic character. Its electrical resistivity measured in the ordered region with the current flowing within the tetragonal plane is governed by the scattering of the conduction electrons on antiferromagnetic spin-wave excitations. The electrical resistivity of single-crystalline NpCuOP shows semimetallic character. It is dominated by a pronounced hump at low temperatures, which likely arises owing to long-range magnetic ordering below about 90 K. Density of state analyses using the local spin-density approximation show covalent overlap between AnO and CuP layers of the structure and dominant contributions from 5f-actinide orbitals at the Fermi level. Calculations on a 2 × 2 × 2 supercell of NpCuOP show ferromagnetic ordering within the Np sheets and complex coupling between these planes. Comparisons of the physical properties of these AnCuOP compounds are made with those of the family of related tetragonal uranium phosphide compounds.

Introduction

Studies of the physical and chemical properties of solid-state nonoxide Np analogues of U and Pu compounds are essential for understanding the early actinide elements and their 5f-electrons. These first few elements of the actinide series embody the transition from itinerant to localized 5f-electrons or, in chemical terms, from resembling the transition metals to resembling the rare-earth elements. Whereas the properties of Np binaries are generally intermediate between those of U and Pu, few ternary or quaternary compounds of Np have been synthesized and investigated thoroughly. Knowledge of the structure−function relationship in such Np compounds can lead to enhanced understanding of the early actinide series; comparison of the properties of isostructural compounds can also lead to enhanced understanding of their unique properties.

The U parent compounds UP$_2$$_{1-9}$ and UCuP$_2$$_{10-13}$ have been well-studied, whereas the analogous Np/P compounds are unknown. The actinide oxypnictogenides AnO$_n$P$_m$$_{14-18}$ and pnictide-chalcoxides AnT$_n$O$_p$$_{19-23}$ (An = U and Np; T = P, As, Sb; Q = S, Se, Te) also belong to this family; they show diverse physical properties. Only the heavier pnictides (T = As, Sb, and Bi) are known to form NpT$_2$$_{24-25}$. The properties of cubic NpP and NpAs are similar;$^{26,27}$ one can speculate that the properties of the unknown NpP$_2$ compound might resemble those of tetragonal NpAs$_2$.$^{28-31}$ NpP$_4$ is said to be isostructural to cubic Th$_3$P$_4$.$^{32,33}$ but the lattice parameter remains unpublished. U and Cu form a second oxyhydride compound, the quaternary U$_2$CuOP$_3$$_{34}$ (initially characterized as U$_2$CuP$_3$$_{35,36}$), that can be viewed as a stacking along [001] of structural blocks from UCuOP and UCu$_2$P$_2$. A few intermetallic Np/Cu compounds are known$^{37-41}$ that are related to superconducting PuCoGa$_4$.$^{42}$

Herein we present the syntheses and properties of UCuOP and the new Np analogue NpCuOP, including crystal structures, electrical resistivities, neutron diffraction and temperature-dependent magnetic susceptibility of UCuOP, and theoretical electronic structures. Concurrent with this work a related study on UCuOP and ThCuOP has appeared.$^{43}$

Experimental Section

Syntheses. Caution! $^{237}$Np and any ingrown daughter products are α- and γ-emitting radioisotopes and as such are considered a health risk. Their use requires appropriate infrastructure and personnel trained in the handling of radioactive materials. The procedures we use for the syntheses of Np compounds have been described.$^{44}$ $^{238}$U was handled under normal laboratory conditions.

The following reagents were used as obtained from the manufacturer: Cu (Aldrich, 99.5%), CuO (Aldrich, 99.99%), and P (Aldrich, 99%). Reactants available in the laboratory were utilized as a transport reagent. Depleted $^{238}$U turnings from Oak Ridge National Laboratory (ORNL) were powdered through three cycles of hydrogenation/dehydrogenation at 573 and 723 K, respectively.$^{45}$ The purity of the resultant U powder was confirmed by powder X-ray diffraction methods.$^{237}$Np chucks were crushed and used as provided (ORNL).

Synthesis of UCuOP. The original synthesis$^3$ of UCuOP involved the reaction of UP and CuO, followed by vapor transport with I$_2$ to afford single crystals. Attempted synthesis of UCuOP using this method was unsuccessful. Here a reaction mixture of 40.0 mg of UCuO powder (0.17 mmol), 8.9 mg of CuO (0.11 mmol), 3.6 mg of Cu (0.056 mmol), and 6.9 mg of P (0.22 mmol) was loaded into a fused-silica ampule in an Ar-filled drybox. The ampule was evacuated to $\sim$10$^{-4}$ Torr and flame-sealed. It was then placed in a computer-controlled furnace, heated to 1273 K in 12 h, kept at 1273 K for 96 h, and cooled in three steps, at 5 K/h to 773 K, at 10 K/h to 473, and finally air cooled.

A powder X-ray diffraction pattern of the resultant uniform black powder confirmed the presence of UCuOP. The sample was loaded into a fused-silica ampule with 9.5 mg I$_2$. It was evacuated to $\sim$10$^{-4}$ Torr and sealed. The ampule was placed in a computer-controlled two-zone furnace where a 50 K temperature gradient (1173–1223 K) was held for 120 h. The sample was then cooled to 873 K in 87.5 h, further cooled at 10 K/h to 753 K,

References

and finally air-cooled. Thin black rectangular plates of UCuOP were obtained in moderate yield, but because most of the single crystals synthesized were too small to be extracted cleanly from the product mixture, the extracted yield was less than 5 wt %. The crystals used for characterization and property measurements were manually extracted from the product mixture.

**Synthesis of NpCuOP.** A reaction mixture of 20.1 mg of Np (0.084 mmol), 6.7 mg of CuO (0.084 mmol), and 2.6 mg of P (0.084 mmol) was loaded into a fused-silica ampule and placed in a computer-controlled furnace where it was heated to 823 K in 8 h, kept at 823 K for 24 h, and finally cooled at 3.67 K/h to 298 K. The resultant black powder was reloaded into a fused-silica ampule with 4 mg of L2. It was evacuated to ∼10⁻⁴ Torr and sealed. It was then placed in a computer-controlled furnace, heated to 1073 K in 24 h, kept at 1073 K for 96 h, cooled at 3.6 K/h to 473 K, and finally cooled at 3.67 K/h to 298 K. The resultant black powder was reloaded into a fused-silica ampule with 4 mg of L2. It was evacuated to ∼10⁻⁴ Torr, flame-sealed, and placed in a computer-controlled furnace where it was heated to 823 K in 8 h, kept at 823 K for 120 h, cooled at 6.42 K/h to 373 K, before finally being air cooled to room temperature. Thin black rectangular plates of NpCuOP were obtained in moderate yield, but as with UCuOP most of the crystals were very small making a clean separation from the product mixture difficult. The estimated yield of separated mass was less than 5 wt %. The crystals used in characterization were manually extracted from the product mixture.

**Structure Determinations.** Single-crystal X-ray diffraction data for UCuOP were collected with the use of graphite-monochromatized Mo Kα radiation (λ = 0.71073 Å) on a Bruker Smart-1000 CCD diffractometer at 153 K. The crystal-to-detector distance was 5.023 cm. The data-collection strategy was determined by the program COSMO to enable collection out to 2θ = 80° with high redundancy and 100% completeness.47 The resultant strategy consisted of 0.3° scans in o for a total of 4042 frames with 15 s/frame exposure times. The collection of the intensity data was carried out with the program SMART.47 Cell refinement and data reduction were carried out with the use of the program SAINT.47 and a face-indexed absorption correction along with incident beam and decay corrections were performed numerically with the use of the program SADABS.47 Single-crystal X-ray diffraction data for NpCuOP were collected with the use of graphite-monochromatized Mo Kα radiation (λ = 0.71073 Å) on a Bruker APEX II CCD diffractometer at 100 K. The crystal-to-detector distance was 5.106 cm. The collection of the intensity data, data refinement, and data reduction were carried out with the program APEX2.48 A face-indexed absorption correction along with incident beam and decay corrections were performed numerically with the use of the program SADABS.47 The structures of both compounds were solved with the direct-methods program SHELXS and refined with the least-squares program SHELXL.40 The program STRUCTURE TIDY49 was then employed to standardize the atomic coordinates in each structure. Table 1 provides details of the crystal data and refinements. Further details may be found in Supporting Information.

**Bond Valence Calculations.** Bond valences were calculated from the standard parameters.36

**Magnetic Susceptibility of UCuOP.** DC magnetic susceptibility measurements on single crystals of UCuOP were carried out with the use of a Quantum Design PPMS5 SQUID magnetometer. The sample comprised 2.69 mg of isolated single crystals of UCuOP that were ground and loaded into a gelatin capsule. Between 3 and 300 K zero-field-cooled and field-cooled susceptibility measurements were collected with a 500 G applied field. The diamagnetic contribution of the sample holder was determined from field versus magnetization measurements to be 1 × 10⁻⁶ emu and subtracted before further analysis. The susceptibility data in the paramagnetic region were fit to the Curie–Weiss equation χ = C/(T − θp), where C is the Curie constant and θp is the Weiss constant. The effective magnetic moment was calculated through the equation μeff = (7.997 C)⁴/³ μB. Owing to constraints on synthesis and separation procedures, collection of NpCuOP single crystals in acceptable quantities for magnetic susceptibility measurements proved to be impossible.

**Electrical Resistivities.** The electrical resistivity and the magnetoresistivity of a single crystal of UCuOP were measured in the temperature range 0.4–300 K and in a magnetic field up to 9 T by a conventional AC four-probe technique employing a Quantum Design PPMS platform. At the lowest temperatures, the electrical current of 100 μA was used in order to avoid heating of the sample. The current was gradually increased with increasing temperature up to the value of 3 mA at room temperature. The measured sample was a small thin platelet of the dimensions 0.5 mm × 0.11 mm × 0.01 mm. The specimen was mounted on a 0.1 mm thick sapphire plate with the use of GE/IMI 7031 varnish (Cambridge Magnetic Refrigeration). Its surface was mechanically polished using cerium oxide powder in order to remove contaminations. Subsequently, four contact pads were made using resistive sintering of indium. Then, droplets of the sulfate were placed on the exposed pads and deposition of the copper onto the sample surface was facilitated by touching these areas with indium wires. The electrical leads (30 μm thick silver wires) were attached to the so-prepared pads with silver paint. The electrical resistivity of a single crystal of NpCuOP was measured between 2.0 and 300 K with a Quantum Design PPMS. A small rectangular plate-like crystal of NpCuOP, of dimensions 0.031 mm × 0.02 mm × 0.065 mm, was mounted along [010] with two leads in a standard linear arrangement. The leads were constructed of 15 μm diameter Cu wire and 8 μm diameter graphite fibers that were attached with Dow 4929N silver paint. Because the minimum resistance of the sample was found to be approximately 0.16 Ω, it was assumed that the lead resistance was negligible.

**Neutron Diffraction Measurements on UCuOP.** Neutron diffractometer experiments on UCuOP were performed on the G4.1 diffractometer installed at the Orphée reactor. The diffractometer

| Table 1. Crystal Data and Structure Refinements for UCuOP and NpCuOPa |
|-------------------------|-------------------------|-------------------------|
| UCuOP                  | NpCuOP                  |
| Fw                     | 348.54                  | 347.51                  |
| a (Å)                  | 3.7817(4)               | 3.7731(4)               |
| c (Å)                  | 8.225(1)                | 8.189(1)                |
| V (Å³)                 | 117.63(2)               | 116.58(2)               |
| T (K)                  | 153(2)                  | 100(2)                  |
| ρθ (g cm⁻³)            | 9.840                   | 9.900                   |
| μ (cm⁻¹)               | 780.79                  | 537.37                  |
| R(Fo)                  | 0.0335                  | 0.0199                  |
| Rw(Fo)                 | 0.0775                  | 0.0476                  |

a For both structures Z = 2; space group = P4/mmm; λ = 0.71073 Å; Rp = ∑(|Fo| - |Fc|)/|Fo| for F > 2σ(Fo), Rw = ∑(|Fo| - |Fc|)²/|Fo|² for F > 2σ(Fo), Σw(Fo)²/Fw = 0.036 for UCuOP and 0.0278 for NpCuOP; w⁻¹ = σ²(Fo)² for Fw < 0.
was equipped with a 800-cell multidetector system. A continuous-flow He-Ne system was used. Diffraction patterns were recorded within the 2θ range of 6°-80° at temperatures of 2 K, 100 K, and 228 K with neutrons of wavelength λ = 2.4255 Å. In addition, the intensities of the strongest magnetic reflections were carefully measured at several temperatures below $T_N$. The analysis of experimental data was made with use of the program FULLPROF. These data may be found in Supporting Information.

**Theoretical Calculations.** Previous theoretical methods, including the molecular field\(^{51}\) and random phase Green’s function\(^{52}\) approximations, have been used to investigate the magnetic properties of compounds in the present tetragonal family. The application of current ab initio density functional methods using fully relativistic Dirac linear muffin-tin orbitals (LMTO) has been applied to the ferromagnetic hexagonal compound UCP\(^{53}\) and ferromagnetic UCuP\(^{54}\), but to our knowledge DFT methods have not been applied to the more complex antiferromagnetically ordered tetragonal phases. Theoretical methods similar to the ones applied here have recently been utilized in the superconducting LaFeOP system to determine band structure, Fermi surfaces, and covalency of the layered structure.\(^{55}\)

Here, periodic spin-polarized band structure calculations were performed with the first principles DFT program Vienna ab initio simulation package (VASP) applying pseudopotentials with a plane-wave basis.\(^{56-58}\) The exchange-correlation potential was chosen as the generalized gradient approximation (GGA) in a projector augmented wave (PAW) method.\(^{60}\) Final self-consistent calculations on single unit cells also included spin orbit coupling (SOC) because the effects of such coupling can be very large for 5f orbitals and are known to shift their energies greatly. SOC was not extended to the eight unit-cell calculations owing to insufficient computing power. Automatically generated Monkhorst-Pack grids were used to carry out Brillouin zone integrations.\(^{61}\) For single unit-cell calculations $6 \times 6 \times 6$ $k$-point meshes were chosen for relaxations and total energy calculations; these were increased to $11 \times 11 \times 11$ $k$-point meshes to establish convergence, density of states (DOS), and charge distribution analysis. For the calculation of a $2a \times 2b \times 2c$ supercell of NpCuOP $4 \times 4 \times 2$ $k$-point meshes were chosen and increased to $6 \times 6 \times 2$ to ensure convergence. Total relaxation convergence was established when forces on each atom relaxed below 0.02 eV/Å. With inclusion of SOC, the spin density was now coupled to the orbital angular momentum; hence, the positive (α) and negative (β) magnetization densities were coupled to the lattice vectors, and both spin ($M_s$) and orbital ($M_L$) contributions to the total magnetization ($M$) were calculated. $M_L$ quenching was avoided by not including symmetry in all SOC calculations.\(^{55}\) In order to retain the global magnetic (antiferromagnetic (AF) or ferromagnetic (F)) character of the DOS, the positive or negative density on any given atom for a given set of angular momentum numbers was summed independently of magnetization direction. The partial (pDOS) and total DOS were then found by independently summing all positive or negative density on each atom and for all atoms, respectively. The addition of the Hubbard U parameter to the current calculations could have served to shift the Fermi energies and alter the p-d-f hybridization. However, it was not included.

The electrons described as core in the PAW potentials were those composed of [Xe]5d\(^{10}\) for U leaving 14 valence elections per atom as 5f\(^6\)p\(^1\)d\(^7\)s\(^7\). [Xe]5d\(^{10}\)f\(^3\) for Np leaving 15 valence elections per atom as 5f\(^6\)p\(^1\)d\(^7\)s\(^7\). For Cu leaving 11 valence electrons per atom as d\(^{9}\)s\(^1\), [He] for O leaving 6 electrons as 2s\(^2\)p\(^2\), and [Ne] for P leaving 5 electrons as 3s\(^2\)p\(^2\). Calculations were conducted on an 8-atom periodic crystallographic unit cell in the tetragonal space group P4/mmm, relaxing atomic positions within the 100 K (NpCuOP) and 153 K (UCuOP) unit cells. Owing to the unknown magnetic properties of NpCuOP, initial electronic-spin relaxations allowed for a starting moment on either one Np or one Cu to propagate throughout the unit cell. Information from these single unit-cell calculations assisted in determining the magnetic alignment in the larger supercell calculations.

The magnetic alignment of the shortest Np–Np interaction was constrained in the one unit-cell calculation by the periodic boundaries. Extension of the calculations to a $2a \times 2b \times 2c$ supercell (8 unit cells, 64 atoms, 592 electrons) removed the ferromagnetic constraint on the closest Np atoms. The difference in energy between magnetic states was small and convergence was reached very slowly. The previously described method of magnetic moment projection proved to be problematic. Thus, additional model ferromagnetic and antiferromagnetic alignments were initialized. Four models were constructed wherein the Np layers were ferromagnetic but were stacked in different configurations: AFII (− + − −), AFIII (− − − −), and ferromagnetic F (− + + +). Examples of antiferromagnetic ordering within the An layers have not been demonstrated for this series of compounds, but for completeness model AFIV was initialized with the first and second closest Np–Np interactions having opposite spins.

Oxidation states were investigated through the use of electron density surfaces determined by volume integration with the use of both “Wigner Seitz radii” $R_w$ and Bader’s topological atom method.\(^{64,65}\) Rather than dividing space into hard spheres ($R_w$), the approach of Bader is to divide space into atomic regions determined by zero-flux charge-density surfaces.\(^{54}\) The accuracy of the charge distribution was established by increasing the size of the fast-Fourier-transform mesh until the difference in Bader charge on an atom between any two calculations was less than 0.003 electrons. Using these two methods, we define the oxidation state as the difference between the number of valence electrons contained within a volume and the number assigned to the neutral atom. The values of $R_w$ were initially set to the standard crystal radii\(^{66}\) of the atom and manipulated to maximize the percentage of the unit cell volume contained by the spheres. The final radii used were UCpCuOP: 1.5 Å for U, 1.1 Å for Cu, 1.5 Å for O, and 1.8 Å for P; NpCuOP: 1.31 Å for Np, 1.25 Å for Cu, 1.5 Å for O, and 1.9 Å for P. In addition to oxidation state analysis, $R_{WS}$ integrations were utilized within VASP for the separation of charge for pDOS and local magnetic moment determinations.

**Results**

**Experimental Structure.** The low-temperature (153 K) structure of UCpOP determined here differs very little

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**Notes:**

from those previously determined at room temperature. NpCuOP at 100 K is isostructural with the U compound; the change in z-coordinates of the An and P atoms sitting on the 2c Wyckoff positions is less than 0.002 Å. Crystallographic and refinement information can be found in Table 1. As in the previously determined structures, the An atoms are coordinated to four O and four P atoms forming a distorted square antiprism. The antiprisms face share in the c-direction (Figure 1). The face- and edge-sharing interactions generate two relatively short An–An interactions of 3.7817(4) and 3.8129(9) Å.

Because the bonding in UCuOP was described previously, comparisons of metrical data (Table 2) to those in other compounds are made only for NpCuOP. The Np–O interatomic distance at 2.3139(3) Å is comparable to those found in NpO2 (2.3539(3) Å) and NpP (2.3073(1) Å). The Np–P interatomic distance at 2.967(1) Å is longer than that in NpPS (2.777 Å) or NpP (2.8073(1) Å). The face-sharing interaction in the \( ab \)-plane generates four short intralayer An–An interactions, \( J_1 \), at 3.7731(4) Å. As with the cation–anion interactions, this Np–Np interaction is shorter but comparable to those of NpOS (3.8088(3) Å) and NpPS (3.807 Å). It is much shorter than that of NpP (3.970 Å) or NpAs2 (3.930 Å). In the edge-sharing c-direction the interlayer Np–Np distance, \( J_2 \), is only slightly longer than the intralayer distance at 3.7813(6) Å. As NpOS crystallizes in the related PbFCl structure-type, this same edge-sharing interaction is present at 3.7902(4) Å. The Cu–Cu distance is 2.6680(3) Å and the Np–Cu distance is 3.3387(4) Å. The Np–Cu distance is longer than that in the intermetallic compound NpCu2Ge2 (3.2666(7) Å) but shorter than that in NpCu4Al4 (3.359(1) Å).

Table 2. Selected Interatomic Distances (Å) and Angles (deg) for UCuOP and NpCuOP

<table>
<thead>
<tr>
<th></th>
<th>UCuOP</th>
<th>NpCuOP</th>
</tr>
</thead>
<tbody>
<tr>
<td>An–O × 4</td>
<td>2.3286(4)</td>
<td>2.3139(3)</td>
</tr>
<tr>
<td>An–P × 4</td>
<td>2.968(2)</td>
<td>2.965(1)</td>
</tr>
<tr>
<td>An–Cu × 4</td>
<td>3.3403(6)</td>
<td>3.3387(4)</td>
</tr>
<tr>
<td>An–An × 4</td>
<td>3.781(4)</td>
<td>3.773(4)</td>
</tr>
<tr>
<td>An–An × 4</td>
<td>3.8129(9)</td>
<td>3.7814(6)</td>
</tr>
<tr>
<td>Cu–P × 4</td>
<td>2.932(3)</td>
<td>2.386(2)</td>
</tr>
<tr>
<td>Cu–Cu × 4</td>
<td>2.674(3)</td>
<td>2.669(3)</td>
</tr>
<tr>
<td>O–An–O</td>
<td>70.09(1)</td>
<td>70.41(1)</td>
</tr>
<tr>
<td>O–An–O</td>
<td>108.59(2)</td>
<td>109.24(2)</td>
</tr>
<tr>
<td>O–An–P</td>
<td>74.69(6)</td>
<td>75.47(4)</td>
</tr>
<tr>
<td>O–An–P</td>
<td>140.40(3)</td>
<td>140.48(2)</td>
</tr>
<tr>
<td>P–An–P</td>
<td>79.15(6)</td>
<td>79.02(4)</td>
</tr>
<tr>
<td>P–An–P</td>
<td>128.6(2)</td>
<td>128.25(9)</td>
</tr>
<tr>
<td>P–Cu–P</td>
<td>104.4(2)</td>
<td>104.5(1)</td>
</tr>
<tr>
<td>P–Cu–P</td>
<td>112.05(8)</td>
<td>112.01(5)</td>
</tr>
</tbody>
</table>

Some comparative interatomic distances in ThCuOP are Th–O = 2.3892(5), Th–P = 3.060(2), Cu–P = 2.424(3) Å.

In UCuOP the unit-cell volume decreases from 118.4 Å³ at room temperature to 117.63(2) Å³ at 153 K (Table 1). This volume decrease shortens the closest U–U interactions from 3.793(1) at 298 K to 3.7817(4) Å at 153 K. The second closest U–U interaction is also reduced from 3.825(1) to 3.8129(8) Å. The standard crystal radius (a) for eight-coordinate U⁴⁺ is 0.02 Å longer than that for eight-coordinate Np⁴⁺. No differences this large are seen in Table 2; any differences there would actually have been smaller had the two structures been determined at the same low temperature.

**Bond Valences.** The calculated bond valencies for UCuOP are 3.9, 1.3, −2.2, and −2.9 for U, Cu, O, and P, respectively. Such empirical bond-order sums depend solely on available bond lengths. In the present instance, because U⁴⁺ is found more often than U³⁺ in such solid-state compounds the results will probably be biased in favor of U⁴⁺. With that caveat, the results support the formulation of UCuOP as U⁴⁺Cu¹⁺O⁻¹P⁻³. Note that bond valence sums are most closely related to “valency”, i.e., to the number of bonds formed, and not to “charge”. Charge distributions are discussed below.

**Magnetic Susceptibility of UCuOP.** The temperature-dependent magnetic susceptibility (χ) of UCuOP, as determined from ground single crystals, is displayed in Figure 2. In agreement with the previous study on polycrystals, the compound displays antiferromagnetic ordering at 224(2) K, but it is clear that the low temperature (80 K) anomaly reported earlier is neither present in the current sample nor in that measured by Sakai et al. The original analysis of the magnetism of UCuOP has been discussed in three possible origins for the low-temperature upturn and inflection: UCuP₂ impurities, UCuP₂ and UCuOP crystal intergrowth, or spin canting intrinsic to UCuOP. Even though small changes in synthesis of the current sample could lead to different types of crystals and a lack of UCuP₂ and UCuOP intergrowth, it seems more likely that the original sample contained trace quantities of UCuP₂ that were undetectable by powder X-ray diffraction methods.

Application of the Curie–Weiss law to the paramagnetic region between 244 and 300 K yields an estimation of the effective moment \( \mu_{\text{eff}} = 2.82(2) \mu_B \). This moment is smaller than \( \mu_{\text{eff}} \) calculated from free-ion moments for...
Matthiesen rule applies, then resistivity from defects and the spin-disorder resistivity.9

The parameter $\mu_{\text{eff}}$ and assist in assigning oxidation states is problematic in solid-state actinide compounds where the effects of crystal-field splitting can be very pronounced.

On the other hand, from measurements on a single crystal, Sakai et al.43 found $T_N = 220$ K with values of $\mu_{\text{eff}} = 3.6 \mu_B$ for the field along the $a$ and $c$ axes. The corresponding Weiss temperatures are $-1000$ and $-60$ K, respectively. The magnitude of $\chi$ in the paramagnetic region above $T_N$ is about twice that measured along the $c$ axis in the present study although at 4.2 K there is little difference. This may reflect differences in the two samples.

**Electrical Resistivities.** The temperature-dependent electrical resistivities in the basal plane ($i \parallel c$) of UCuOP and NpCuOP single crystals are displayed in Figures 3 and 4, respectively. Both display resistive anomalies in the low-temperature regions that are similar to those seen in UP$_2$ and U$_2$CuOP$_3$.9,36,71

The basal plane resistivity ($\rho_{i\parallel}$) of UCuOP displayed in Figure 3 is very similar to that of UP$_2$9 and U$_2$CuOP$_3$10 measured for the same configuration of the electrical current with respect to the crystallographic axes. At 299 K, the resistivity is 745 $\mu\Omega$ cm. In the paramagnetic region, between 205 and 300 K, the resistivity can be fit to the equation

$$\rho_{i\parallel} = A + c_{\text{ph}} T,$$

where $A = 668.6(3) \mu\Omega$ cm and $c_{\text{ph}} = 0.253(2) \mu\Omega$ cm/K. If we assume that the Matthiesen rule applies, then $A$ is the sum of the residual resistivity from defects and the spin-disorder resistivity.9

The parameter $c_{\text{ph}}$ describes the resistance from electron–phonon drag; its value is an order of magnitude higher than that of UP$_2$ (0.073 $\mu\Omega$ cm/K).9 Below 80 K, the resistivity can be fit to the formula $\rho_{i\parallel} = \rho_0 + c_m T^2 \exp(-\Delta/T)$, appropriate for the antiferromagnetically ordered region probed by the electric current flowing perpendicular to the magnetic moments. Here $\rho_0$ stands for the residual resistivity and $\Delta$ represents a gap in the spin-wave spectrum. The least-squares fitting yielded the parameters $\rho_0 = 211.7(2) \mu\Omega$ cm, $c_m = 0.028(1) \mu\Omega$ cm/K$^2$, and $\Delta = 10.5(3)$ K. Subtracting $\rho_0$ from $A$ gives an estimate of the spin-disorder resistivity at high temperatures to be about 457 $\mu\Omega$ cm.

A plot of the derivative of resistivity with respect to temperature (inset Figure 3) exaggerates the effect of magnetic ordering on the resistivity and allows for the determination of $T_N$. The resultant value of $T_N$ is approximately 10 K below the value of 224 K determined from the magnetic data. The difference between these two temperatures can be attributed to the somewhat different sensitivities of the two properties to short-range magnetic order.36 At a magnetic field of 9 T, the value of $T_N$ is reduced to 204 K. Reduction of the critical temperature with the application of magnetic field is a characteristic feature of antiferromagnets.

The transverse magnetoresistance (MR) of UCuOP displayed in Figure 5, defined as $MR = [\rho(B) - \rho(B = 0)] / \rho(B = 0)] \times 100\%$, measured with the electric current flowing in the basal tetragonal plane and the magnetic field applied along the $c$-axis. The MR response is very small; its absolute value does not exceed 1% in 9 T for any temperature. In the paramagnetic state, MR is negative and varies approximately as $B^2$. In the ordered region,
one observes a change in the sign of MR from positive at low temperatures to negative close to $T_N$, and the MR isotherms also have a $B^2$-like shape. Such a behavior is characteristic of antiferromagnetic systems.\(^{72}\)

Sakai et al.\(^{43}\) have also measured the electrical resistivity of a single crystal of UCuOP. Their results exhibit an order of magnitude higher resistivity than the present study and an abrupt increase just below $T_N$ which is not present in our results. These differences once again may reflect differences in the two samples or be a manifestation of the experimental procedures. Surface oxidation, which would lead to higher resistance, was scrupulously avoided in our study; sample preparation was not discussed by Sakai et al.

The measured basal-plane resistivity of NpCuOP is nearly 640 m$\Omega$ cm at 298 K. This value can be compared to the resistivity of single-crystalline NpAs$_2$ of only 95 $\mu$Ω cm at 298 K.\(^{10}\) Even though the resistance of the leads in this two-probe measurement does contribute to the overall resistivity, it should be low compared to the large resistivity determined here. Down to about 90 K, $\rho_{11}$ hardly changes with temperature. Below this temperature the $\rho_{11}(T)$ curve forms a broad hump, reminiscent of the behavior of antiferromagnets possessing magnetic unit cells larger than their crystallographic unit cells. This characteristic anomaly in the electrical conduction arises from excess conduction electron scattering on the “magnetic Brillouin zone” boundaries. As shown in the inset to Figure 4, the derivative of the resistivity of NpCuOP with respect to temperature exhibits a sharp minimum at 90 K. The shape of this feature suggests the hypothesis that the compound undergoes a transition into an antiferromagnetically ordered state. Similar behavior has been reported, for example, for antiferromagnetic U$_2$Cu$_3$OP$_5$,\(^{71}\) yet in the latter compound it occurs for the resistivity measured along the tetragonal $c$-axis, whereas for NpCuOP it is observed for the basal plane. It is unfortunate that the limited availability of NpCuOP prevents further experimental studies; any quantitative analysis of its interesting electronic and magnetic properties is not possible at this time.

**Neutron Diffraction Measurements on UCuOP.** Neutron diffraction powder data led to a crystal structure for UCuOP that is in good agreement with those determined by X-ray diffraction single-crystal methods here and previously.\(^3\) The magnetic diffraction patterns taken at 2 and 100 K were fully indexable on the basis of the chemical unit cell. The observed additional (101) magnetic reflections are characteristic of collinear antiferromagnetic ordering of the AFI type. Thus, the magnetic structure of UCuOP consists of ferromagnetic (001) layers of U atoms stacked along [010] in the sequence ++ + −. The magnetic moments are also aligned along [001]. At 2 K the uranium magnetic moment is 2.42(6) $\mu_B$. The temperature dependence of the (100) magnetic peak intensity is shown in Figure 6. It yields a value of $T_N$ of about 220 K, in agreement with the results from magnetic susceptibility measurements.

**Theoretical Relaxed Ionic and Magnetic Structures.** During relaxation of the atoms within the 153 K crystallographic unit cell of UCuOP, the U atoms moved less than 0.02 Å toward the O layer and the P atoms moved less than 0.004 Å toward the Cu layer. The Cu and O layers remained stationary owing to symmetry constraints. After the relaxed positions in the LSDA + GGA method were determined, SOC was implemented. Taking the crystallographic [010] as the axis of magnetization, antiferromagnetic total magnetic moments of 1.40 $\mu_B$ and $M_L = 2.03 \mu_B$, both aligned along [010], were found for the two U atoms. The electronic configuration of U using $R_{WS}$ values was $6d^{8.85}5f^{2.6}$, whereas for Cu it was $3d^{8.9}$. These values clearly approach $5f^3$ for $U^{3+}$ and $3d^9$ for $Cu^{2+}$. For $Cu^{2+}$ a magnetic moment is expected, but the calculated magnetic moment here was only 0.004 $\mu_B$. At 1.40 $\mu_B$, the total U magnetic moments were nearly half the experimental value of 2.42(6) $\mu_B$ by neutron diffraction measurements. However, the calculated U moment is considerably less than the free ion moments of 3.58 $\mu_B$ for $U^{3+}$ and 3.62 $\mu_B$ for $U^{4+}$, in agreement with the experiments. The reason for the underestimated total moment may well lie in errors in the calculated coupling between orbital (L) and spin (S) moments, which in the present scheme is done perturbatively. The fact that the Cu d-electron count is less than 10 $e^-$ is not necessarily an indicator of localized magnetization; in fact, the partial density of states and charge maps show strong Cu–P covalency (see below). In this case the local exchange interaction, which would favor a Cu moment, is overwhelmed by...
the stronger ligand field. Incorporation of the Hubbard U term for electron–electron coupling could increase the magnetic moments, but to do this is beyond the scope of the present work. In addition, the magnetic moments and f-electron counts are dependent on the selected $R_{WS}$ values. Increasing $R_{WS}$ could increase the per-U magnetic moments but would also increase overlap with O and P and cause double counting of electrons.

**Single Unit Cell of NpCuOP.** When a moment on one Np or Cu atom was allowed to propagate throughout one crystallographic unit cell, then only the Np atoms possessed significant magnetization greater than $0.1 \mu_B$. The crystallographic unit cell contains two An positions so two magnetic configurations are possible, ferromagnetic and antiferromagnetic. During relaxation of the atoms within the 100 K crystallographic unit cell of NpCuOP, the Np atoms moved toward the central O layer by 0.01 Å for the antiferromagnetically (AF) aligned and 0.03 Å for the ferromagnetically (F) aligned configuration. The P atoms moved toward the Cu layer and away from the Np atoms by 0.02 Å for the AF calculation and 0.01 Å for the F calculation. Cu and O atoms were again stationary owing to symmetry constraints.

Taking the [001] crystallographic axis as the axis of magnetization for both AF and F cases, we found the F model to be lower in energy by 35 meV. Before the in-magnetization for both AF and F cases, we found the F owing to symmetry constraints. The atoms moved toward the Cu layer and away from the Np or Cu atom was allowed to propagate throughout one crystallographic unit cell, then only the Np atoms possessed significant magnetization greater than $0.1 \mu_B$. The crystallographic unit cell contains two An positions so two magnetic configurations are possible, ferromagnetic and antiferromagnetic. During relaxation of the atoms within the 100 K crystallographic unit cell of NpCuOP, the Np atoms moved toward the central O layer by 0.01 Å for the antiferromagnetically (AF) aligned and 0.03 Å for the ferromagnetically (F) aligned configuration. The P atoms moved toward the Cu layer and away from the Np atoms by 0.02 Å for the AF calculation and 0.01 Å for the F calculation. Cu and O atoms were again stationary owing to symmetry constraints.

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**Supercell Calculations on NpCuOP.** In order to remove the ferromagnetic constraint on the nearest Np–Np interaction, $J_1$, the calculations were extended to a $2a \times 2b \times 2c$ supercell. The relative energies of each magnetic model for the supercell calculations may be found in Table 4. In these five models for NpCuOP in a $2a \times 2b \times 2c$ supercell, the ferromagnetic alignment (F) of Np CuOP, the Np atoms moved toward the central O layer by 0.01 Å for the antiferromagnetically (AF) aligned and 0.03 Å for the ferromagnetically (F) aligned configuration. The P atoms moved toward the Cu layer and away from the Np atoms by 0.02 Å for the AF calculation and 0.01 Å for the F calculation. Cu and O atoms were again stationary owing to symmetry constraints. The Np movement was slightly larger than in

<table>
<thead>
<tr>
<th>NpCuOP</th>
<th>AF</th>
<th>AF</th>
<th>AF</th>
<th>AF</th>
<th>F</th>
</tr>
</thead>
<tbody>
<tr>
<td>$\Delta E$</td>
<td>2.92</td>
<td>2.26</td>
<td>0.79</td>
<td>2.87</td>
<td>0.00</td>
</tr>
<tr>
<td>$M_b$</td>
<td>3.0(1)$^a$</td>
<td>3.0(4)</td>
<td>3.15(6)</td>
<td>3.03(10)</td>
<td>3.10(6)</td>
</tr>
</tbody>
</table>

$^a$ Magnetization direction taken as [001].

**Density of States of UCuOP.** A plot of the total DOS and partial DOS (pDOS) including spin–orbit coupling for each atom type in UCuOP is found in Figure 7. The states surrounding the Fermi energy, $E_F$, (set to 0 eV) from approximately $-2.5$ to $2 eV$ are dominated by U states with small contributions from all other species. The contribution from the U-6d orbitals in this region is small suggesting minimal hybridization with the U-5f orbitals. The states above $-0.5 eV$ are almost exclusively those from 5f-states where there are five regions of band overlap (peaks), one below and four above $E_F$. The increased

<table>
<thead>
<tr>
<th>$z$</th>
<th>AF</th>
<th>AF</th>
<th>AF</th>
<th>AF</th>
<th>F</th>
</tr>
</thead>
<tbody>
<tr>
<td>1/6</td>
<td>3.16(1)</td>
<td>3.12(1)</td>
<td>3.22(5)</td>
<td>3.10(8)</td>
<td>3.16(1)</td>
</tr>
<tr>
<td>1/3</td>
<td>3.11(1)</td>
<td>3.3(6)</td>
<td>3.18(5)</td>
<td>3.14(6)</td>
<td>3.14(7)</td>
</tr>
<tr>
<td>1/2</td>
<td>2.94(1)</td>
<td>2.62(1)</td>
<td>3.09(1)</td>
<td>2.95(1)</td>
<td>3.05(1)</td>
</tr>
<tr>
<td>5/6</td>
<td>2.93(2)</td>
<td>2.9(2)</td>
<td>3.10(1)</td>
<td>2.94(2)</td>
<td>3.04(1)</td>
</tr>
</tbody>
</table>

$^a$ Standard deviations are large owing to differences in neighboring layers of Np atoms.
width of the peak below $E_F$ is due to partial overlap of filled bands of $f_{xz}$ and $f_{yz}$ character. Above $E_F$ the majority component of the four peaks is from empty $f_{x}(x^2-y^2)$ and $f_{zxy}$ states and antibonding $f_{xz}$ and $f_{yz}$ states. The $f_{y}(3x^2-r^2)$, $f_{2}$, and $f_{2}(x^2-y^2)$ states are partially filled forming wide bands ranging from approximately $-0.5$ to $0.8$ eV. Their antibonding states overlap with those of $f_{xz}$ to form the highest plotted bands at $1.3$ eV.

The symmetric nature of total DOS results from the summed contributions from both $\alpha$- and $\beta$-magnetizations. For atom U1 (3/4, 3/4, 0.34) the majority bands at $E_F$ are $\alpha$-states, but the unoccupied antibonding states above $E_F$ have $\beta$-magnetization, inset to Figure 7. $E_F$ crosses the bands at a region of high $\alpha$-magnetization density suggesting UCuOP is actually semimetallic within the U layers. The small $\beta$-density at approximately $0.12$ eV suggests a complex interaction between $\alpha$- and $\beta$-states and consequently the AF aligned U-layers. Incorporation of an onsite Coulomb correction term would likely split these f-bands, but as the resistivity displays complex metallic-like character it is possible the overlap would be retained. Shifting of sub-bands around $E_F$ would occur, with changes in the absolute value of the DOS at $E_F$. However, it is doubtful that a simple counting of states is adequate to describe any transport property of such a heavy fermion system. It must be kept in mind that the Hubbard U parameter must presently be considered as empirical and adjusted to fit some physical property.

Figure 7. Total DOS and pDOS for UCuOP. The Fermi level is at 0 eV. Inset displays pDOS for magnetically coupled U1, P1, and Cu1 atoms surrounding the Fermi energy.

Between $-2.5$ and $-0.5$ eV is a region of enhanced interaction between U, P, and Cu. The contribution from P has both p- and d-character that is significantly coupled to the U density. This can be seen in the inset to Figure 7 where along with the pDOS of U1, those of P1 (1/4, 1/4, 0.18) and Cu1 (3/4, 1/4, 0) are plotted. The P 3p majority states are stabilized and shifted to lower energy by overlapping with the U 5f-states, whereas the P 3p minority states are shifted to higher energy mirroring the U 5f (above $E_F$). There are contributions from several f-orbitals at this energy, but the major contribution is fittingly from $f_{zxy}$ as the lobes of the axially quantized representation for this orbital point toward the corners of a cube. It should interact with the P electrons in an $\sigma$-bonding fashion. The P density at this energy is also coupled to the Cu layer where the pDOS of Cu1 displays a similar shifting of the majority $\alpha$-states to lower binding energy whereas the minority $\beta$ are shifted slightly higher. Figure 8 is a three-dimensional representation of the magnetization density; the coupling between U and P can clearly be seen in the small lobe (blue) above P1 and toward the itinerate U-f density around U1 (red). A similar amount of magnetization is located around the O atoms, but they are coupled to both $\alpha$- and $\beta$-magnetization f-density. The coupling between U1 and Cu1 is likely the result of super exchange through P.

The majority of the Cu-3d states are located between $-4.5$ and $-2.5$ eV and overlap with the P-3p states that extend down to $-7$ eV. The region from approximately $-7$ to $-4.5$ eV contains contributions from all species, but the major contribution is from the O and P anions. The four regions of overlap at higher binding energies are mainly from U-anion overlap. The peak and shoulder at approximately $-11$ eV are from P-3s density with small contributions from both Cu and U. The three regions between $-25$ and $-14.5$ eV are predominately from overlap of U-6p, O-2s, and O-2p-states. As with the U-P overlap near $E_F$, the density at these higher binding energies is also asymmetric within a ferromagnetically aligned
The states surrounding the Fermi level from approximatively 16 to 14.5 eV are from U-6p overlap with both O-2s (16 to 14.5 eV) and O-2p (17.5 to 16 eV). There is also a small contribution from the P-3s and P-3p in this region. The two regions at approximately 20 and 25 eV are again from U-6p and O-2s, but there are no contributions from the O-2p state.

**Density of States of NpCuOP.** A plot of the DOS and pDOS including spin–orbit coupling for an F single unit cell of NpCuOP can be found in Figure 9. As in UCuOP, the states surrounding the Fermi level from approximately −0.5 to 3 eV are predominately 5f states, but the contributions from the other species are much more significant. The significant Np 6d contributions in this region mirror the shape of the 5f-states and suggest some degree of 5f-6d hybridization. In the U compound, the 5f-orbitals were further split allowing differentiation of the orbitals into filled, partially filled, and empty states, but in the Np analogue the 5f states form almost completely degenerate wide bands with contributions from all the orbitals in each DOS peak near E_F. The partially filled Np-5f bands at E_F and the shifting of the minority (β) magnetization states to above E_F suggest that NpCuOP is also semimetallic. Even though there is extensive evidence of hybridization of the orbitals at E_F, the higher binding energy overlap regions are similar to those found in UCuOP. The features between −0.5 and −2 eV are from overlap of Np, Cu, and P bands where the majority α-states are stabilized in energy, whereas the β-states are shifted to higher energy. Even though the contribution from all Np f-orbitals at this energy is much more evenly divided than are the f-orbitals of U, the f_{xy} orbital again has the largest contribution. The enhanced asymmetry in the P-pDOS between −12 and −10 eV emphasizes the AF coupling of these p-states with Np as the β-states are stabilized to lower energy whereas the α-states are shifted to higher binding energies. The AF coupling of the magnetization density is also evident in the three-dimensional representation of the magnetization density, Figure 10, where the itinerant Np magnetization density forms layers in the (001) plane (red), and the other atoms are surrounded by density of magnetization opposite that of the Np ions (blue).

**Comparison of DOS between 4f and 5f Compounds.** The electronic states surrounding the Fermi level in these actinide compounds are very different from those calculated for the isostructural rare-earth oxypnictide compounds. Calculations on LaFeOP, LaFeOAs, and LnFeOAs (Ln = La, Ce, Pr, Nd, Sm, and Y) show the Fermi energy to be dominated by Fe-3d states, whereas the Ln-4f states are much higher in binding energy. An extensive ab initio study found that rare-earth substitution should have very little effect on the electronic structure, and suggested that any magnetic interactions between Ln and FeAs layers would be weak. The limited involvement of the rare-earth in the properties of these compounds is also emphasized by the observation of superconductivity not only in the LnFeOAs compounds but also in the related AFe_2As_2 (A = K, Cs, K/Sr, Cs/Sr, Ba, and Sr) compounds. The electronic properties of the actinide compounds investigated here are dominated by the 5f states at the Fermi energy and by the magnetic ordering of the 5f-electrons. The Cu-3d states in these compounds are pushed down below the Fermi level where they overlap with O-2p and P-3p states. The more diffuse 5f-orbitals also show enhanced overlap with both O and P states at the Fermi energy and at higher binding energies when compared to Ln-O or Ln-P overlap. As such, none of these rare-earth or actinide structures should be viewed as containing isolated LnO or AnO and MT layers.

**Theoretical Charge Distribution.** Assignment of formal oxidation states in actinide compounds is complicated by delocalization of 5f-electrons and covalent bonding. The calculated average charge on each atom from both \( R_{WS} \) integration and the Bader topological method may be found in Table 6. The charges determined from \( R_{WS} \) are over one electron short of the total for both compounds; this suggests considerable delocalization into the interstitial region. Therefore, Bader charges are now discussed.

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Calculation of formal oxidation states using the Bader charges gives unreasonable formal oxidation states of approximately $\text{An}^{2+}$ and $\text{Cu}^{0.2+}$. Summing the calculated charges over the AnO and CuP layers is more informative. Two formal oxidation-state models $\text{An}^{4+}/\text{Cu}^{1+}$ and $\text{An}^{3+}/\text{Cu}^{2+}$ are supplied in Table 6. The sum of charges within the AnO layers for both compounds approaches the model for $\text{An}^{3+}/\text{Cu}^{2+}$ with only an extra 0.15 e$^{-}$ for UO and 0.23 e$^{-}$ for NpO. Previous use of this method for LaFeOP determined a difference between the model and Bader charges of 0.36 e$^{-}$ extra in the LaO layer that was attributed to La-P covalent interactions. The relation-ship between the magnitude of the charge difference and the degree of covalency in an An-P bond is unclear, but the covalency of Np-P seems to be intermediate between La-P and U-P.

Discussion

Figure 11 displays the basic structures of the family of actinides that includes the current compounds as well as those of the parent and other related compounds. Previous discussions of this family of compounds have centered around division of a structure into different building blocks stacked in the c-direction. In all of the related tetragonal compounds, the An atoms sit at $C_{4v}$ centers of symmetry with eight anions in the first coordination sphere forming a square antiprism (Figure 11). For AnT$_2$ and AnPS compounds, there is an additional ninth capping anion interaction not retained in AnOS or any of the Cu-filled structures, but it has been omitted from the figure for the sake of clarity.

In all the compounds, the actinide square antiprisms face share in the ab-plane generating short An-An distances discussed above and listed in Table 7 as $J_1$. These interatomic distances are important to the electronic and magnetic properties and are exceedingly close to the Hill limit for U of 3.4 Å for direct 5f orbital overlap. However, the differences in the properties of these compounds must be related to some additional structural difference in the second or third An coordination sphere. The stacking of the square antiprisms along the c-axis in UP$_2$, AnTQ, AnOS, AnCuOP, and the U CuOP-like U position of U$_2$Cu$_2$OP$_3$ is edge sharing that we designate as a Type I interaction. In U CuP$_2$ and the second U position of U$_2$Cu$_2$OP$_3$, this interaction is face sharing and designated here as Type II. Even though a clear crystal-field splitting model, such as that used in d-element chemistry, cannot easily be drawn for the f-orbitals in $C_{4v}$ symmetry, the face-sharing interaction along the 4-fold major axis that is present only in the Type II compounds should lead to enhanced overlap of the 5f$_{z^2}$ orbital. Because these longer An-An interactions have an effect on the properties of these compounds, they have been listed in Table 7 as $J_2$ and $J_3$, where $J_2$ is the edge- or face-sharing interaction and $J_3$ is the interaction across the empty tetrahedral holes or the Cu-layer.

The compounds UP$_2$, UOS, NpOS, and U$_2$Cu$_2$OP$_3$ all contain Type I interactions, as found in UCuOP. Those five compounds order antiferromagnetically at 203 K, 755 K, 4.2 K, and 146 K, and 224 K, respectively. With the


nomenclature devised earlier, the stacking sequence of ferromagnetically aligned actinide layers along the c-axis may be described as AFII (−−−) in UP$_2$, AFIII (+−−) in UOS, and AFI (−−−) in UCuOP. More complex AF ordering is found in U$_2$Cu$_2$OP$_3$ (Type I and II), but between Type I U layers the ordering is AF. The magnetic structure of NpOS remains unknown but is assumed to be that of NpOSe, AFI. In these compounds $J_1$ is ferromagnetic whereas the shorter of $J_2$ and $J_3$ is antiferromagnetic (Table 7). The ratio $J_3/J_2$ is much closer to unity in UP$_2$ and UOS than it is in UCuOP. This may be why the magnetic unit cells of UP$_2$ and UOS are $a \times b \times 2c$, but the crystallographic and magnetic cells coincide in UCuOP.

In UP$_2$ and UOS, the formation of a larger magnetic unit cell decreases the size of the Brillouin zone thereby changing the shape of the Fermi surface and directly affecting the electronic properties. The magnetic-resistive interaction is clearest in UP$_2$ where the resistivity within the ferromagnetic basal plane ($\rho_z$) increases with temperature until $T_N$ and then becomes nearly temperature independent. Conversely, the longitudinal resistivity ($\rho_l$) (AF direction) displays a characteristic “hump backed” trend, increasing with temperature and reaching a maximum at approximately 120 K before decreasing until $T_N$ (203 K). Even though UOS displays insulating resistivity in the high-temperature paramagnetic region, its larger magnetic unit cell could lead to similar trends in the ordered low-temperature regions. Longitudinal resistivity of U$_2$Cu$_2$OP$_3$ also shows a similar “hump backed” increase that is centered around 43 K and levels off at approximately 200 K. This is consistent with an antiferromagnetic structure similar to that of UP$_2$ but with a larger number of F ordered layers along the c-direction.

Of the two compounds with Type II interactions, namely, UCuP$_2$ and U$_2$Cu$_2$OP$_3$, the former orders ferromagnetically at 74.5 K and displays typical ferromagnetic temperature-dependent resistivity. Complex antiferromagnetic ordering in the latter compound leads to anisotropy in its susceptibility and to a low-temperature increase at ~80 K. Temperature-dependent resistivity also fits well with the low-temperature “hump-back” in the longitudinal resistivity and with metallic conductivity in the ordered region with the characteristic “knee” at the Néel point for the basal-plane resistivity. Neutron diffraction experiments on U$_2$Cu$_2$OP$_3$ show the Type I interactions are AF, whereas the Type II are F. The stacking of two Type I and two Type II layers leads to +−−−−−−−−−−−−+ stacking of the U layers. The AF interactions are across the O layer and between Type I U layers, whereas the Type I U layer orders F with its closest Type II U layer. The antiferromagnetically ordered Type I U$_1$ ions order with 2.2 $\mu_B$ moments but the ferromagnetically ordered Type II U$_2$ ions order with 1.1 $\mu_B$ moments. Even though this change in magnitude might suggest mixed valence U, the compound charge balances with all tetravalent U though this change in magnitude might suggest mixed valence U, the compound charge balances with all tetravalent U.

The properties of UCuOP determined in this work fit well into the framework described above for this family of compounds. Because the U sheets in UCuOP order ferromagnetically, it is not surprising that resistivity within this layer mirrors that of UP$_2$ and UCuP$_2$. Even though UOS is a semiconductor in the paramagnetic region, resistivity measurements in the ordered region might be revealing because

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**Table 6. Calculated Total Atomic and Layer Charges ($e^*$) for UCuOP and NpCuOP**

<table>
<thead>
<tr>
<th>species</th>
<th>$R_{WS}$ charge$^b$</th>
<th>Bader charge</th>
<th>purely ionic $\text{An}^{n+}/(\text{Cu}^{1+})$</th>
<th>purely ionic $\text{An}^{n+}/(\text{Cu}^{1+})$</th>
</tr>
</thead>
<tbody>
<tr>
<td>U</td>
<td>9.69</td>
<td>11.94</td>
<td>10</td>
<td>11</td>
</tr>
<tr>
<td>Cu</td>
<td>9.33</td>
<td>10.83</td>
<td>10</td>
<td>9</td>
</tr>
<tr>
<td>P</td>
<td>7.68</td>
<td>6.01</td>
<td>8</td>
<td>8</td>
</tr>
<tr>
<td>O</td>
<td>7.67</td>
<td>7.22</td>
<td>8</td>
<td>8</td>
</tr>
<tr>
<td>UO</td>
<td>17.35</td>
<td>19.15</td>
<td>18</td>
<td>19</td>
</tr>
<tr>
<td>CuP</td>
<td>17.01</td>
<td>16.85</td>
<td>17</td>
<td>17</td>
</tr>
<tr>
<td>Np</td>
<td>11.52</td>
<td>13.04</td>
<td>11</td>
<td>12</td>
</tr>
<tr>
<td>Cu</td>
<td>8.92</td>
<td>10.82</td>
<td>10</td>
<td>9</td>
</tr>
<tr>
<td>P</td>
<td>7.30</td>
<td>5.95</td>
<td>8</td>
<td>8</td>
</tr>
<tr>
<td>O</td>
<td>7.96</td>
<td>7.18</td>
<td>8</td>
<td>8</td>
</tr>
<tr>
<td>NpO</td>
<td>19.48</td>
<td>20.23</td>
<td>19</td>
<td>20</td>
</tr>
<tr>
<td>CuP</td>
<td>16.22</td>
<td>16.77</td>
<td>18</td>
<td>17</td>
</tr>
</tbody>
</table>

$^a$ Maximum total charge is 36 $e^*$ for UCuOP and 37 $e^*$ for NpCuOP.
$^b$ $R_{WS}$ values (Å): UCuOP: U, 1.5; Cu, 1; O, 1.5; P, 1.8; NpCuOP: Np, 1.31; Cu, 1.25; O, 1.5; P, 1.9.
the structure and interatomic distances are closer to those of UCuOP but it orders magnetically in the longer range AFIII manner. The semimetallic resistivity of UCuOP also fits well with the present LSDA $+$ GGA $+$ SOC calculations that find the DOS at $E_F \neq 0$ to be asymmetric with respect to electron spin. Even though addition of an on-site Coulomb correction could shift the location of $E_F$ and split the 5f orbitals, this should not change the semimetallic conduction within each ferromagnetic U sheet. Comparative electronic structure calculations on other antiferromagnetic compounds of this family are needed.

Owing to the very limited number of known Np/P compounds and minimal knowledge of their properties, structure–property comparisons cannot be made. Nonetheless, the intriguing properties of the known compounds, including those reported here, strongly suggest that the electronic structures of isostructural Np and U compounds are very different. The trend in the basal-plane resistivity found here for NpCuOP suggests antiferromagnetic ordering, but it more closely resembles the longitudinal resistivity of the antiferromagnetic U compounds. Even though the calculated DOS for the lowest-energy ferromagnetically aligned single unit cell of NpCuOP resembles that of UCuOP, the increased Cu moment in NpCuOP compared to that in UCuOP and the charge distribution within the AnO layers of NpCuOP suggest an intermediate nature of NpCuOP between that of LaFeOP and UCuOP. The supercell calculations suggest increased complexity for the magnetic alignment of Np atoms in NpCuOP. As the number of multinary compounds of Np increases, our understanding of this intermediate actinide and the entire actinide series will also increase.

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**Supporting Information Available:** The crystallographic files in CIF format for UCuOP and NpCuOP as well as the neutron diffraction data for UCuOP. This material is available free of charge via the Internet at http://pubs.acs.org.